

Vishay General Semiconductor

Surface Mount TRANSZORB[®] Transient Voltage Suppressors



PRIMARY CHARACTERISTICS					
V _{WM} 5.0 V					
P _{PPM}	100 W				
I _{FSM}	25 A				
T _J max. 150 °C					

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units specifically for protecting 5.0 V supplied sensitive equipment against transient overvoltages.

FEATURES

- Very low profile typical height of 0.68 mm
- Ideal for automated placement
- Oxide planar chip junction
- Uni-directional polarity only
- Peak pulse power: 100 W (10/1000 μs)
- ESD capability: 15 kV (air), 8 kV (contact)
- Meets MSL level 1, per J-STD-020C, LF maximum peak of 260 °C
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Halogen-free

MECHANICAL DATA

Case: MicroSMP

Molding compound meets UL 94V-0 flammability rating.

Base P/N-E3 - RoHS compliant, commercial grade

Base P/NHE3 - RoHS compliant, high reliability/ automotive grade (AEC-Q101 qualified)

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, high reliability/automotive grade (AEC-Q101 qualified)

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test, HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation ⁽¹⁾⁽²⁾	P _{PPM}	100	W			
Peak pulse current with a 10/1000 µs waveform (Fig. 1)	I _{PPM}	10.9	А			
Non repetitive peak forward surge current 10 ms single half sine-wave ⁽²⁾	I _{FSM}	25	А			
Power dissipation $T_L = 120 \ ^{\circ}C^{(2)}$	PD	1.0	W			
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 150	°C			

Notes:

(1) Non-repetitive current pulse, per Fig. 1

(2) Mounted on 6.0 x 6.0 mm copper pads to each terminal



COMPLIANT



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)										
DEVICE TYPE	DEVICE MARKING CODE		TAGE TI _T ⁽¹⁾	TEST CURRENT I _T (mA)	STAND-OFF VOLTAGE V _{WM} (V)	MAXIMUM REVERSE LEAKAGE AT V _{WM} Ι _D (μΑ)	V _C (V) A1	-	CLAN VOLTA	AGE ⁽²⁾ ⁻ I _{PPM} (A)
MSP5.0A	AE	6.40	7.07	10	5.0	100	9.2	10.9	14.5	57

Notes:

(1) Pulse test: $t_p \le 50 \text{ ms}$

(2) Surge current waveform per Fig. 1 and derate per Fig. 2

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Typical thermal resistance ⁽¹⁾	R _{θJA} R _{θJL}	125 30	°C/W		

Note:

(1) Thermal resistance from junction to ambient and junction to lead mounted on P.C.B. with 6.0 x 6.0 mm copper pad areas.

 $R_{\theta JL}$ is measured at the terminal of cathode band.

IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS ($T_A = 25 \ ^{\circ}C$ unless otherwise noted)							
STANDARD	TEST TYPE TEST CONDITIONS SYMBOL CLASS VALUE						
AEC-Q101-001	Human body model (contact mode)	C = 100 pF, R = 1.5 k Ω	V	H3B	> 8 kV		
IEC-61000-4-2 ⁽²⁾	Human body model (air discharge mode) ⁽¹⁾	C = 150 pF, R = 150 Ω	Ω V _C 4 > 15 kV				

Notes:

(1) Immunity to IEC-61000-4-2 air discharge mode has a typical performance > 30 kV

(2) System ESD standard

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
MSP5.0A-E3/89A	0.006	89A	4500	7" diameter plastic tape and reel			
MSP5.0AHE3/89A ⁽¹⁾	0.006	89A	4500	7" diameter plastic tape and reel			
MSP5.0A-M3/89A	0.006	89A	4500	7" diameter plastic tape and reel			
MSP5.0AHM3/89A ⁽¹⁾	0.006	89A	4500	7" diameter plastic tape and reel			

Note:

(1) High reliability/automotive grade (AEC-Q101 qualified)



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RATINGS AND CHARACTERISTICS CURVES

 $(T_A = 25 \ ^{\circ}C \text{ unless otherwise noted})$

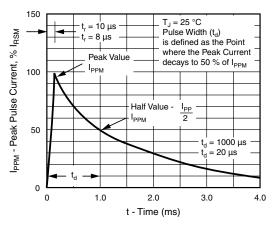


Figure 1. Pulse Waveform

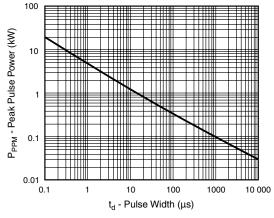
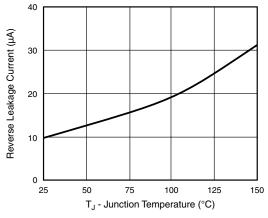
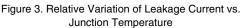


Figure 2. Peak Pulse Power Rating Curve





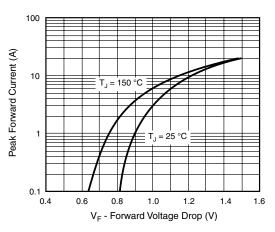


Figure 4. Typical Peak Forward Voltage Drop vs. Peak Forward Current

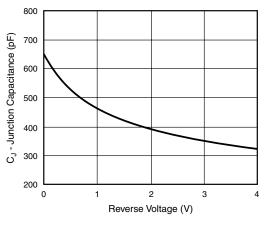
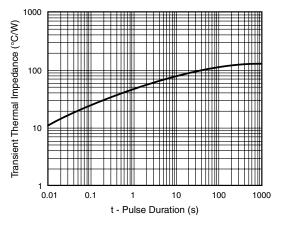
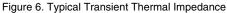


Figure 5. Typical Junction Capacitance





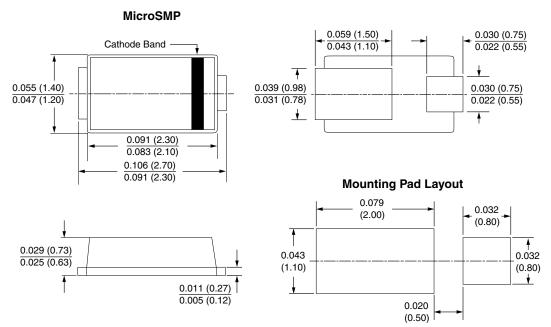
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MSP5.0A

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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